








	<h2>IPD65R600C6</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">IPD65R600C6</a></p> <p><b>Hersteller / Marke:</b> <a href="#">International Rectifier (Infineon Technologies)</a></p> <p><b>Teil der Beschreibung:</b> IPD65R600C6 Infineon Technologies</p> <p><b>Datenblätter:</b>  <a href="#">IPD65R600C6.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 37213 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">IPD65R600C6</a>
Hersteller	<a href="#">International Rectifier (Infineon Technologies)</a>
Beschreibung	IPD65R600C6 Infineon Technologies
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	37213 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	63W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.3A (Tc)
Rds On (Max) @ Id, Vgs	600 mOhm @ 2.1A, 10V
VGS (th) (Max) @ Id	3.5V @ 210µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	440pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

IPD65R600C6 ist neu im Original, Suche IPD65R600C6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD65R600C6 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD65R600C6: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>IPD65R420CFDAATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH TO252-3</p>	 <p><b>IPD65R600E6ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 650V 7.3A TO252-3</p>	 <p><b>IPD65R600C6ATMA1</b> International Rectifier (Infineon Technologies) LOW POWER_LEGACY</p>	 <p><b>IPD65R600E6</b> INFINEO IPD65R600E6 INFINEO</p>
 <p><b>IPD65R420CFDATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 650V 8.7A TO252</p>	 <p><b>IPD65R420CFDBTMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 650V 8.7A TO252</p>	 <p><b>IPD65R600E6BTMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 650V 7.3A TO252-3</p>	 <p><b>IPD65R600C6BTMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 650V 7.3A TO252</p>

### heiße Teile

Mehr

 IPD60R380C6	 IPD60R380E6	 IPD60R380P6	 IPD60R385CP	 IPD60R3K3C6
 IPD60R400CE	 IPD60R450E6	 IPD60R520C6	 IPD60R520CP	 IPD60R600C6
 IPD60R600CP	 IPD60R600E6	 IPD60R600P6	 IPD60R750E6	 IPD60R800CE
 IPD60R950C6	 IPD64N06LG	 IPD64CN10NG	 IPD65R1K4C6	 IPD65R250C6
 IPD65R250E6	 IPD65R380C6	 IPD65R380E6	 IPD65R420CFD	 IPD65R420CFDA
 IPD65R600E6	 IPD65R660CFD	 IPD65R950C6	 IPD65R950CFD	 IPD70N03S4L-04
 IPD70N03S4L04XT	 IPD70N04S3-07	 IPD70N10S3-12	 IPD70N10S3L-12	 IPD70P04P4-09
 IPD70P04P4L-08	 IPD75N04S4-06	 IPD78CN10NG	 IPD800N06NG	 IPD80N04S3-06
 IPD80N04S3-06B	 IPD80N06S3-09	 IPD80P03P4L-07	 IPD80R1K0CE	 IPD80R1K4CE
 IPD85P04P4L-06	 IPD90N03S4L-02	 IPD90N03S4L-03	 IPD90N04S03-04	 IPD90N04S3-04

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